

# 14.2-Gbps Quad Channel, Dual Mode Linear Equalizer

Check for Samples: SN65LVCP1414

#### **FEATURES**

- Quad Channel, Uni-Directional, Multi-Rate, Dual-Mode Linear Equalizer with Operation up to 14.2Gbps Serial Data Rate for Backplane and Cable Interconnects
- Linear Equalization Increases Link Margin for Systems Implementing Decision Feedback Equalizers (DFE)
- 17dB Analog Equalization at 7.1GHz with 1dB Step Control for Backplane Mode or Cable Mode
- Output Linear Dynamic Range: 1200mV
- Bandwidth: >20GHz Typical
- Better than 15dB Return Loss at 7.1GHz
- Supports Out-of-Band (OOB) Signaling
- Low Power, Typically 80mW per Channel at 2.5V VCC
- 38-Terminal QFN (Quad Flatpack, No-Lead) 5 mm x 7 mm x 0.75 mm, 0.5 mm Terminal Pitch
- Excellent Impedance Matching to 100Ω
   Differential PCB Transmission Lines
- GPIO or I<sup>2</sup>C Control
- 2.5V and 3.3V±5% Single Power Supply
- 2kV ESD (HBM)
- Flow-Through Pin-Out Provides Ease of Routing
- Small Package Size Saves Board Space
- Low Power

#### **APPLICATIONS**

- High Speed Links in Telecommunication and Data Communication
- Backplane and Cable Interconnects for 10GbE, 16GFC,10G SONET, SAS, SATA, CPRI, OBSAI, Infiniband, 10GBase-KR, and XFI/SFI

#### DESCRIPTION

The SN65LVCP1414 is an asynchronous, protocolagnostic, low latency, four-channel linear equalizer optimized for use up to 14.2Gbps and compensates for losses in backplane or active cable applications. The architecture of the SN65LVCP1414 is designed to work with an ASIC or FPGA with digital equalization employing Decision Feedback Equalizers The SN65LVCP1414 linear equalizer preserves the shape of the transmitted signal DFE performance. ensuring optimum SN65LVCP1414 provides a low power solution while at the same time extending the effectiveness of DFE.

The SN65LVCP1414 is configurable via I<sup>2</sup>C or GPIO interface. Using the I<sup>2</sup>C interface of the SN65LVCP1414 enables the user to control independently the Equalization, Path Gain, and Output Dynamic Range for each individual channel. In GPIO mode, Equalization, Path Gain, and Output Dynamic Range can be set for all channels using the GPIO Input pins.

The SN65LVCP1414 outputs can be disabled independently via I<sup>2</sup>C.

The SN65LVCP1414 operates from a single 2.5V or 3.3V power supply.

The package for the SN65LVCP1414 is a 38 pin 5-mm x 7-mm x 0.75-mm QFN (Quad Flat-pack Nolead) lead-free package with 0.5mm pitch and is characterized for operation from -40°C to 85°C.



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

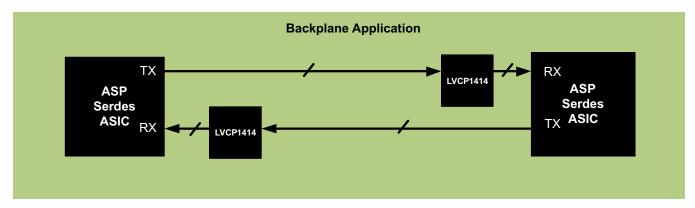


Figure 1. Typical Backplane Application - Trace Mode

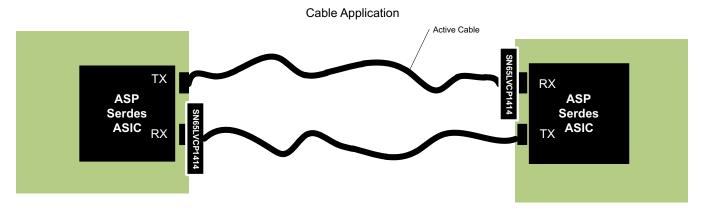


Figure 2. Typical Cable Application - Cable Mode



### Block Diagram (GPIO or I<sup>2</sup>C Mode)

A simplified block diagram of the SN65LVCP1414 is shown in Figure 3 for GPIO or I<sup>2</sup>C input control mode. This compact, low power, 14.2Gbps quad-channel dual-mode linear analog equalizer consists of four high-speed data paths and an input GPIO pin logic-control block and a two-wire interface with a control-logic block.

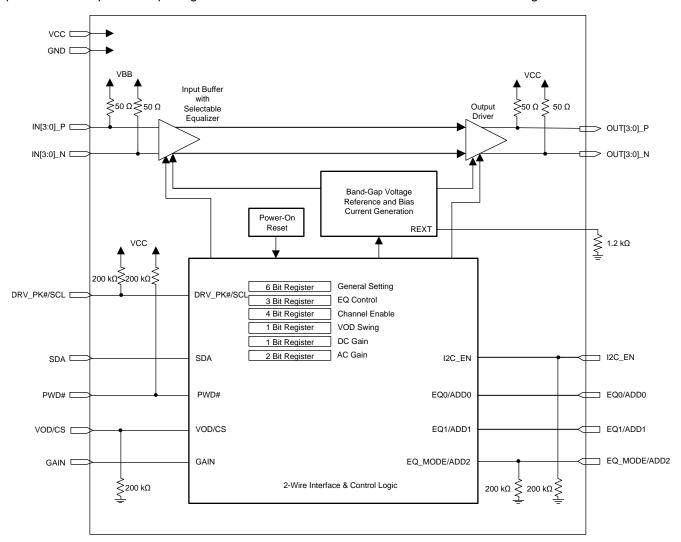


Figure 3. Simplified Block Diagram of the SN65LVCP1414

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#### **Package**

The package pin locations and assignments are shown in Figure 4. The SN65LVCP1414 is packaged in a 5mm x 7mm x 0.75mm, 38 pin, 0.5mm pitch lead-free QFN.

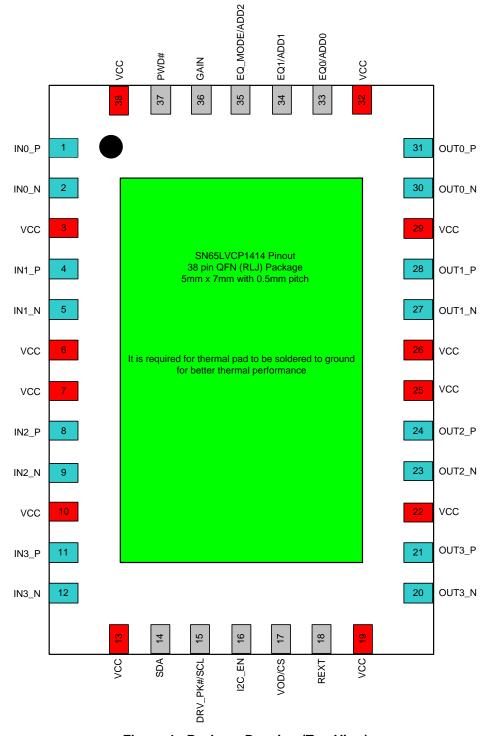


Figure 4. Package Drawing (Top View)

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### **Pin Descriptions**

PINS		DIRECTION TYPE		
NAME	NO.	SUPPLY		DESCRIPTION
DIFFERENTIAL	HIGH-SPE	ED I/O		
IN0_P IN0_N	1 2	Input, (with 50 Ω termination to input common mode)	Differential input, lane 0	
IN1_P IN1_N	4 5	Input, (with 50 Ω termination to input common mode)	Differential input, lane 1	
IN2_P IN2_N	8 9	Input, (with 50 Ω termination to input common mode)	Differential input, lane 2	
IN3_P IN3_N	11 12	Input, (with 50 Ω termination to input common mode)	Differential input, lane 3	
OUT0_P OUT0_N	31 30	Output	Differential output, lane 0	
OUT1_P OUT1_N	28 27	Output	Differential output, lane 1	
OUT2_P OUT2_N	24 23	Output	Differential output, lane 2	
OUT3_P OUT3_N	21 20	Output	Differential output, lane 3	
CONTROL SIGI	NALS			
SDA	14	Input Output, Open drain	GPIO mode No action needed	I <sup>2</sup> C mode I <sup>2</sup> C data. Connect a 10kΩ pull-up resistor externally
DRV_PK#/SCL	15	Input. (with 200kΩ pull-up)	GPIO mode HIGH: disable Driver peaking LOW: enables Driver 6dB AC peaking	I <sup>2</sup> C mode I <sup>2</sup> C clock. Connect a 10kΩ pull-up resistor externally
I2C_EN	16	Input, (wtih 200kΩ pull-down) 2.5V/3.3V CMOS	Configures the device operation for I <sup>2</sup> 0 HIGH: enables I <sup>2</sup> C mode LOW: enables GPIO mode	C or GPIO mode:
VOD/CS	17	Input, (with 200kΩ pull-down) 2.5V/3.3V CMOS	GPIO mode HIGH: set high VOD range LOW: set low VOD range	I <sup>2</sup> C mode HIGH: acts as Chip Select LOW: disables I <sup>2</sup> C interface
REXT	18	Input, Analog	External Bias Resistor: 1,200 Ω to GND	
EQ0/ADD0	33	Input, 2.5V/3.3V CMOS - 3-state	GPIO mode Working with EQ1 to determine input EQ gain.	I <sup>2</sup> C mode ADD0 along with pins ADD1 and ADD2 comprise the three bits of I <sup>2</sup> C slave address. ADD2:ADD1:ADD0:XXX



# Pin Descriptions (continued)

PIN	S	DIRECTION TYPE				DE0	ACRIPTICAL	
NAME	NO.	SUPPLY		DESCRIPTION				
EQ1/ADD1	34	Input, 2.5V/3.3V CMOS - 3-state	GPIO mode Working with E EQ gain steps			I <sup>2</sup> C slave a		
			EQ1	EQ0	EQ GAIN	ADD2:ADI	D1:ADD0:XXX	
			GND	GND	000			
			GND	HiZ	000			
			GND	VCC	001			
			HiZ	GND	010			
			HiZ	HiZ	011			
			HiZ	VCC	100			
			VCC	GND	101			
			VCC	HiZ	110			
			VCC	VCC	111			
			EQ1 and EQ0	works with	AC_GAIN a	and DC_GAI	N to determine final EQ gain as this:	
			EQ1/ EQ0	GAIN	DC GAIN (dB)	EQ GAIN (dB)		
			000 ~ 111	LOW	-6	1 ~ 9		
			000 ~ 111	HiZ	-6	7 ~ 17		
			000 ~ 111	HiGH	0	1 ~ 9		
EQ_MODE/ ADD2	35	Input, (with 200kΩ pull-down), 2.5V/3.3V CMOS	GPIO mode HIGH: Trace m LOW: Cable me			I <sup>2</sup> C slave a	ng with pins ADD1 and ADD0 comprise the three bits of address. D1:ADD0:XXX	
GAIN	36	Input, 2.5V/3.3V CMOS - 3-state	GPIO mode Work with EQ1 Gain. See table		et total EQ	I <sup>2</sup> C mode No action	needed	
PWD#	37	Input, (with 200kΩ pull-up), 2.5V/3.3V CMOS	HIGH: Normal (LOW: Power do			s off and out	puts disabled, resets I <sup>2</sup> C	
POWER SUPP	PLY							
VCC	3, 6, 7, 10, 13, 19, 22, 25, 26, 29, 32, 38	Power	Power supply 2	2.5V±5%,	3.3V±5%			
GND Center Pad		Ground	the GND plane	. At least	15 PCB vias	are recomm	bottom of the package. This pad must be connected to ended to minimize inductance and provide a solid age) for the via placement.	

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### **Absolute Maximum Ratings**

over operating free-air temperature range (unless otherwise noted)(1)

		VALUES	UNIT
V <sub>CC</sub>	Supply voltage range <sup>(2)</sup>	-0.3 to 4	V
$V_{IN,DIFF}$	Differential voltage between INx_P and INx_N	±2.5	V
V <sub>IN+, IN</sub>	Voltage at Inx_P and flNx_N	-0.5 V to VCC+0.5	V
V <sub>IO</sub>	Voltage on control IO pins	-0.5 V to VCC+0.5	V
I <sub>IN+</sub> I <sub>IN-</sub>	Continuous current at high speed differential data inputs (differential)	-25 to 25	mA
I <sub>OUT+</sub> I <sub>OUT-</sub>	Continuous current at high speed differential data outputs	-25 to 25	mA
FCD	Human Body Model (3) (All Pins)	2.0	kV
ESD	Charged-Device Model (4) (All Pins)	-0.3 to 4 ±2.5 -0.5 V to VCC+0.5 -0.5 V to VCC+0.5 -25 to 25 -25 to 25	V
Moisture sens	sitivity level	3	
Reflow temper	erature package soldering, 4 sec	260	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.
- (3) Tested in accordance with JEDEC Standard 22, Test Method A114-A.
- (4) Tested in accordance with JEDEC Standard 22, Test Method C101.

#### **Thermal Information**

	THERMAL METRIC <sup>(1)</sup>	SN65LVCP1414	LINUTO
	THERMAL METRIC	RLJ (38 PINS)	UNITS
$\theta_{JA}$	Junction-to-ambient thermal resistance (2)	36.9	
$\theta_{JCtop}$	Junction-to-case (top) thermal resistance (3)	22.3	
$\theta_{JB}$	Junction-to-board thermal resistance (4)	10.7	9004
ΨЈТ	Junction-to-top characterization parameter <sup>(5)</sup>	0.3	°C/W
ΨЈВ	Junction-to-board characterization parameter <sup>(6)</sup>	10.6	
$\theta_{JCbot}$	Junction-to-case (bottom) thermal resistance (7)	1.9	

- (1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.
- (2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
- (3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
- (4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
- (5) The junction-to-top characterization parameter,  $\psi_{JT}$ , estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining  $\theta_{JA}$ , using a procedure described in JESD51-2a (sections 6 and 7).
- (6) The junction-to-board characterization parameter, ψ<sub>JB</sub>, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ<sub>JA</sub>, using a procedure described in JESD51-2a (sections 6 and 7).
- (7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.



#### **Recommended Operating Conditions**

		MIN	NOM	MAX	UNIT
dR	Operating data rate			14.2	Gbps
V <sub>CC</sub>	Supply voltage	2.375	2.5	2.625	V
V <sub>CC</sub>	Supply voltage	3.135	3.3	3.465	V
TC	Junction temperature	-10		125	°C
ТВ	Maximum board temperature			85	°C
CMOS DC	SPECIFICATIONS	•		•	
$V_{IH}$	High-level input voltage	0.8×V <sub>CC</sub>			V
V <sub>MID</sub>	Mid-level input voltage	V <sub>CC</sub> ×0.4		V <sub>CC</sub> ×0.6	V
V <sub>IL</sub>	Low-level input voltage	-0.5		0.2×V <sub>CC</sub>	V
PSNR BG	Bandgap circuit PSNR	20			dB

#### **Electrical Characteristics (VCC 2.5V ±5%)**

over operating free-air temperature range, all parameters are referenced to package pins (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT
POWER	RCONSUMPTION					
$PD_L$	Device power dissipation	VOD = LOW at 2.5V VCC with all 4 channels active		317	475	mW
$PD_H$	Device power dissipation	VOD = HIGH, at 2.5V VCC with all 4 channels active		485	675	mW
PD <sub>OFF</sub>	Device power with all 4 channels switched off	Refer to I <sup>2</sup> C section for device configuration. 2.5V VCC		10		mW

<sup>(1)</sup> All typical values are at 25°C and with 2.5V supply unless otherwise noted.

### Electrical Characteristics (VCC 3.3V ±5%)

over operating free-air temperature range, all parameters are referenced to package pins (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN TYP <sup>(1)</sup>	MAX	UNIT
POWER	CONSUMPTION				
$PD_L$	Device power dissipation	VOD = LOW at 3.3V VCC with all 4 channels active	450	625	mW
$PD_H$	Device power dissipation	VOD = HIGH, at 3.3V VCC with all 4 channels active	697	925	mW
PD <sub>OFF</sub>	Device power with all 4 channels switched off	Refer to I <sup>2</sup> C section for device configuration, 3.3V VCC	10		mW

<sup>(1)</sup> All typical values are at 25°C and with 2.5V supply unless otherwise noted.

### Electrical Characteristics (VCC 2.5V ±5%, 3.3V ±5%)

over operating free-air temperature range, all parameters are referenced to package pins (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT
CMOS DO	C SPECIFICATIONS		·			
I <sub>IH</sub>	High level input current	$VIN = 0.9 \times V_{CC}$	-40	17	40	μΑ
I <sub>IL</sub>	Low level input current	$VIN = 0.1 \times V_{CC}$	-40	17	40	μΑ
CML INP	UTS (IN[3:0]_P, IN[3:0]_N)		·			
r <sub>IN</sub>	Differential input resistance	INx_P to INx_N		100		Ω
V <sub>IN</sub>	Input linear dynamic range	Gain = 0.5		1200		$mV_{pp}$
V <sub>ICM</sub>	Input common mode voltage	Internally biased		V <sub>CC</sub> -0.8		V
SCD11	Input differential to common mode conversion	100MHz to 7.1GHz		-20		dB
SDD11	Differential input return loss	100MHz to 7.1GHz		-15		dB

<sup>(1)</sup> All typical values are at 25°C and with 2.5V and 3.3V supply unless otherwise noted.



# Electrical Characteristics (VCC 2.5V ±5%, 3.3V ±5%) (continued)

	PARAMETER	TEST CONDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT
CML OUT	PUTS (OUT[3:0]_P, OUT[3:0]_N)				ļ	-
		$R_L = 100 \Omega$ , $V_{OD} = HIGH$		1200		$mV_{pp}$
$V_{OD}$	Output linear dynamic range	$R_L = 100 \Omega$ , $V_{OD} = LOW$		600		$mV_{pp}$
V <sub>OS</sub>	Output offset voltage	$R_L = 100 \Omega$ , 0 V applied at inputs		10		mV <sub>pp</sub>
V <sub>OCM</sub>	Output common mode voltage	See Figure 5		V <sub>CC</sub> -0.4		V
$V_{CM,RIP}$	Common mode output ripple	K28.5 pattern at 14.2Gbps on all 4 channels, No interconnect loss, VOD = HIGH		10	20	${\sf mV}_{\sf RMS}$
$V_{OD,RIP}$	Differential path output ripple	K28.5 pattern at 14.2Gbps on all channels, No interconnect loss, VIN = 1200mVpp.			20	$mV_{pp}$
V <sub>OC(SS)</sub>	Change in steady-state common- mode output voltage between logic states			±10		mV
t <sub>R</sub>	Rise time <sup>(2)</sup>	Input signal with 30ps rise time, 20% to 80%, See Figure 7		31		ps
t <sub>F</sub>	Fall time (2)	Input signal with 30ps fall time, 20% to 80%, See Figure 7		32		ps
SDD22	Differential output return loss	100MHz to 7.1GHz		-15		dB
SCC22	Common-mode output return loss	100MHz to 7.1GHz		-5		dB
t <sub>PLH</sub>	Low-to-high propagation delay			65		ps
t <sub>PHL</sub>	High-to-low propagation delay	See Figure 6		65		ps
t <sub>SK(O)</sub>	Inter-Pair (lane to lane) output skew (3)	All outputs terminated with 100 Ω, See Figure 8		8		ps
t <sub>SK(PP)</sub>	Part-to-part skew <sup>(4)</sup>	All outputs terminated with 100 $\Omega$			50	ps
r <sub>OT</sub>	Single ended output resistance	Single ended on-chip termination to VCC, Outputs will be AC coupled		50		Ω
r <sub>OM</sub>	Output termination mismatch at 1MHz	$\Delta rom = 2 \times \frac{rp - rn}{rp + rn} \times 100$		5		%
Ch <sub>iso</sub>	Channel-to-channel isolation	Frequency at 7.1GHz	35	45		dB
		10MHz to 7.1GHz, No other noise source present, VOD = LOW		400		μVRMS
OUT <sub>NOISE</sub>	Output referred noise <sup>(5)</sup>	10MHz to 7.1GHz, No other noise source present, VOD = HIGH		500		μVRMS
EQUALIZA	ATION					
EQ <sub>Gain</sub>	At 7.1GHz input signal	Equalization Gain, EQ = MAX	15	17		dB
Vpre	Output pre-cursor pre-emphasis	Input signal with 3.75 pre-cursor and measure it on the output signal, Refer Figure 9. Vpre = 20log(V3/V2)		3.75		dB
Vpst	Output post-cursor pre-emphasis	Input signal with 12dB post-cursor and measure it on the output signal, Refer Figure 9, Vpst = 20log(V1/V2)		12		dB
DJ1	Residual deterministic jitter at 10.3125 Gbps	Transmit Side application Tx launch Amplitude = 0.6Vpp, EQ=0, ACGain and DCgain = Low and VOD = High, Trace Mode Test Channel -> 0", See Figure 11		0.016		Ulp-p
DJ2	Residual deterministic jitter at 10.3125 Gbps	Receive Side Application Tx launch Amplitude = 0.6Vpp, EQ=7, ACGain and VOD = High and DCGain = High, Trace Mode Test Channel -> 12" (9dB loss at 5GHz), See Figure 10		0.11		Ulp-p
DJ3	Residual deterministic jitter at 14.2 Gbps	Transmit Side Application Tx launch Amplitude = 0.6Vpp, EQ=0, ACGain and DCgain = Low and VOD = High, Trace Mode Test Channel -> 0", See Figure 11		0.041		Ulp-p
DJ4	Residual deterministic jitter at 14.2 Gbps	Receive Side Application  Tx launch Amplitude = 0.6Vpp, EQ=7, ACGain and VOD = High and DCGain = High, Trace Mode Test Channel -> 8" (9dB loss at 7GHz), See Figure 10		0.13		Ulp-p

Rise and Fall measurements include board and channel effects of the test environment, refer to Figure 10 and Figure 11.  $t_{SK(O)}$  is the magnitude of the time difference between the channels.  $t_{SK(PP)}$  is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices (3) (4) operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

All noise sources added.



#### **Parameter Measurement Information**

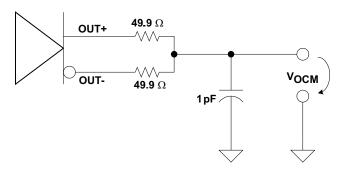


Figure 5. Common Mode Output Voltage Test Circuit

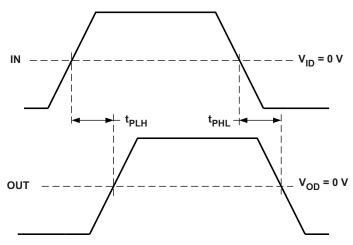


Figure 6. Propagation Delay Input to Output

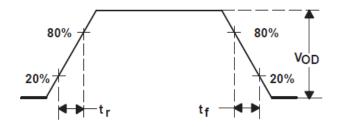


Figure 7. Output Rise and Fall Times

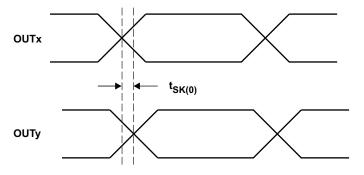


Figure 8. Output Inter-Pair Skew



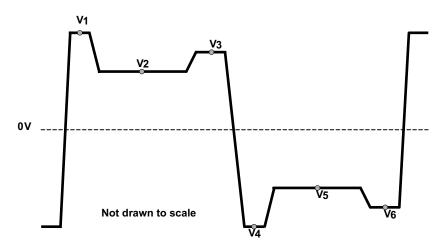


Figure 9. Vpre and Vpost (test pattern is 1111111100000000 (8-1s, 8-0s))

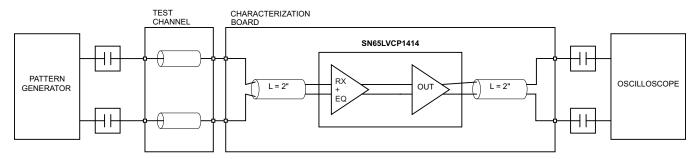


Figure 10. Receive Side Performance Test Circuit

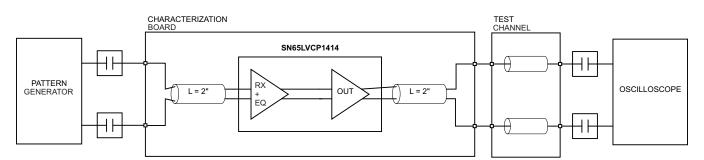


Figure 11. Transmit Side Performance Test Circuit



# **Equivalent Input and Output Schematic Diagrams**

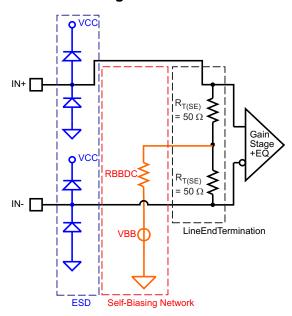


Figure 12. Equivalent Input Circuit Design

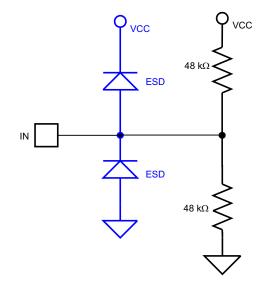


Figure 13. 3-Level Input Biasing Network



#### **Typical Characteristics**

Typical operating condition is at  $V_{CC} = 2.5V$  and  $T_A = 25^{\circ}C$ , no interconnect line at the output, and with default device settings (unless otherwise noted).

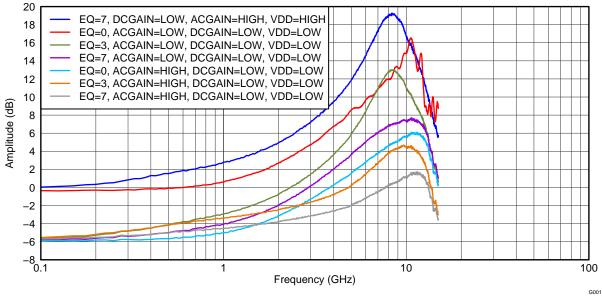
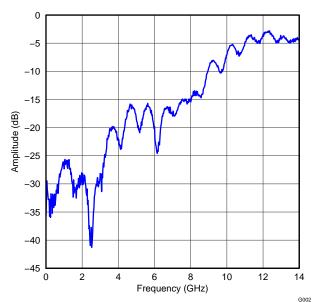


Figure 14. Typical EQ Gain Profile Curve





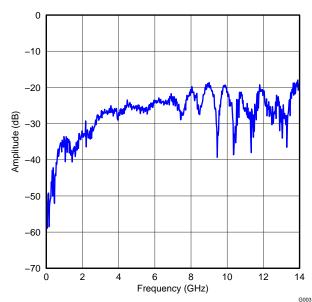


Figure 16. Differential to Common Mode Conversion



### **Typical Characteristics (continued)**

Typical operating condition is at  $V_{CC} = 2.5V$  and  $T_A = 25^{\circ}C$ , no interconnect line at the output, and with default device settings (unless otherwise noted).

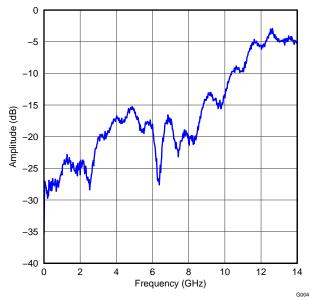
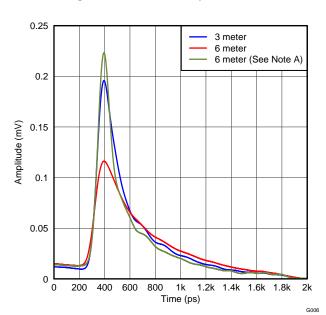


Figure 17. Differential Output Return Loss



A. With SN65LVCP1414 -> EQ = 4, VOD = High, ACGain = HiZ, DCGain = Low

Figure 19. Cable Mode – Symbol Response

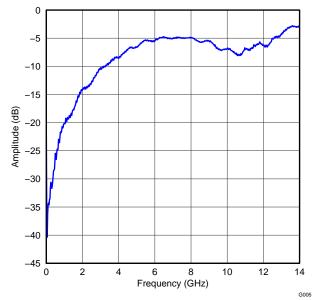
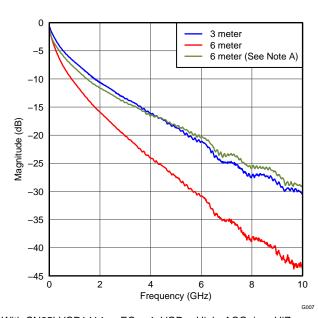


Figure 18. Common Mode Output Return Loss



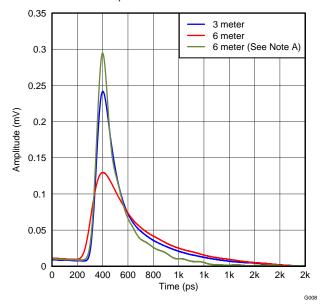
A. With SN65LVCP1414 -> EQ = 4, VOD = High, ACGain = HiZ, DCGain = Low

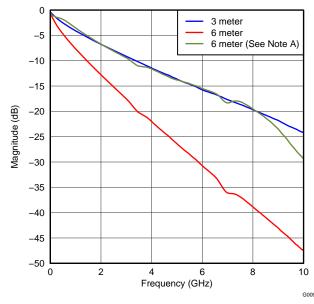
Figure 20. Cable Mode – Frequency Domain



### **Typical Characteristics (continued)**

Typical operating condition is at  $V_{CC} = 2.5V$  and  $T_A = 25^{\circ}C$ , no interconnect line at the output, and with default device settings (unless otherwise noted).





A. With SN65LVCP1414 -> EQ = 7, VOD = High, ACGain = High, DCGain = Low

Figure 21. Trace Mode – Symbol Response

A. With SN65LVCP1414 -> EQ = 7, VOD = High, ACGain = High, DCGain = Low

Figure 22. Trace Mode - Frequency Domain

**Table 1. Control Settings Descriptions** 

MODE	DCGAIN	ACGAIN<1:0>	EQ<2:0>	DC GAIN (dB)	EQ GAIN (dB)	APPLICATION
0	0	0	000 to 111	-6	1 to 9	Short Input Trace; Large Input Swing
0	0	11	000 to 111	-6	7 to 17	Long Input Trace; Large Input Swing
0	1	1	000 to 111	0	1 to 9	Short Input Trace; Small Input Swing
0	1	11	000 to 111	0	2 to 10	Short Input Trace; Small Input Swing
1	0	0	000 to 111	-6	1 to 9	Short Input Cable; Large Input Swing
1	0	11	000 to 111	-6	7 to 17	Long Input Cable; Large Input Swing
1	1	1	000 to 111	0	1 to 9	Short Input Cable; Small Input Swing
1	1	11	000 to 111	0	2 to 10	Short Input Cable; Small Input Swing

**Table 2. Control Settings Descriptions** 

GAIN	DC GAIN	ACGAIN<1:0>
Low	0	00
HighZ	0	11
High	1	01



#### Two-Wire Serial Interface and Control Logic

The SN65LVCP1414 uses a 2-wire serial interface for digital control. The two circuit inputs, SDA and SCL, are driven, respectively, by the serial data and serial clock from a microcontroller, for example. The SDA and SCK pins require external  $10k\Omega$  pull-ups to VCC.

The 2-wire interface allows write access to the internal memory map to modify control registers and read access to read out control and status signals. The SN65LVCP1414 is a slave device only which means that it cannot initiate a transmission itself; it always relies on the availability of the SCK signal for the duration of the transmission. The master device provides the clock signal as well as the START and STOP commands. The protocol for a data transmission is as follows:

- 1. START command
- 2. 7 bit slave address (0000ADD[2:0]) followed by an eighth bit which is the data direction bit (R/W). A zero indicates a WRITE and a 1 indicates a READ. The ADD[2:0] address bits change with the status of the ADD2, ADD1, and ADD0 device pins, respectively. If the pins are left floating or pulled down, the 7 bit slave address is 0000000.
- 3. 8 bit register address
- 4. 8 bit register data word
- 5. STOP command

Regarding timing, the SN65LVCP1414 is I<sup>2</sup>C compatible. The typical timing is shown in Figure 9 and a complete data transfer is shown in Figure 10. Parameters for Figure 9 are defined in Table 3.

Bus Idle: Both SDA and SCL lines remain HIGH

**Start Data Transfer:** A change in the state of the SDA line, from HIGH to LOW, while the SCL line is HIGH, defines a START condition (S). Each data transfer is initiated with a START condition.

**Stop Data Transfer:** A change in the state of the SDA line from LOW to HIGH while the SCL line is HIGH defines a STOP condition (P). Each data transfer is terminated with a STOP condition; however, if the master still wishes to communicate on the bus, it can generate a repeated START condition and address another slave without first generating a STOP condition.

Data Transfer: The number of data bytes transferred between a START and a STOP condition is not limited and is determined by the master device. The receiver acknowledges the transfer of data.

**Acknowledge:** Each receiving device, when addressed, is obliged to generate an acknowledge bit. The transmitter releases the SDA line and a device that acknowledges must pull down the SDA line during the acknowledge clock pulse in such a way that the SDA line is stable LOW during the HIGH period of the acknowledge clock pulse. Setup and hold times must be taken into account. When a slave-receiver doesn't acknowledge the slave address, the data line must be left HIGH by the slave. The master can then generate a STOP condition to abort the transfer. If the slave-receiver does acknowledge the slave address but some time later in the transfer cannot receive any more data bytes, the master must abort the transfer. This is indicated by the slave generating the not acknowledge on the first byte to follow. The slave leaves the data line HIGH and the master generates the STOP condition.

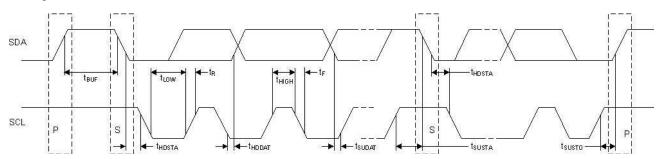


Figure 23. Two-Wire Serial Interface Timing Diagram



# **Table 3. Two-Wire Serial Interface Timing Diagram Definitions**

SYMBOL	PARAMETER	MIN	MAX	UNIT
f <sub>SCL</sub>	SCL clock frequency		400	kHz
t <sub>BUF</sub>	Bus free time between START and STOP conditions	1.3		μs
t <sub>HDSTA</sub>	Hold time after repeated START condition. After this period, the first clock pulse is generated	0.6		μs
$t_{LOW}$	Low period of the SCL clock	1.3		μs
t <sub>HIGH</sub>	High period of the SCL clock	0.6		μs
t <sub>SUSTA</sub>	Setup time for a repeated START condition	0.6		μs
t <sub>HDDAT</sub>	Data HOLD time	0		μs
t <sub>SUDAT</sub>	Data setup time	100		ns
t <sub>R</sub>	Rise time of both SDA and SCL signals		300	ns
t <sub>F</sub>	Fall time of both SDA and SCL signals		300	ns
t <sub>SUSTO</sub>	Setup time for STOP condition	0.6		μs

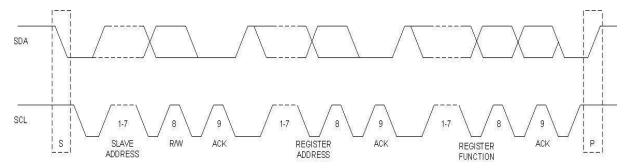


Figure 24. Two-Wire Serial Interface Data Transfer



### **Register Mapping**

The register mapping for read/write register addresses 0 (0x00) through 22 (0x18) are shown in Table 4. Table 5 describes the circuit functionality based on the register settings.

Table 4. SN65LVCP1414 Register Mapping Information

			LVOI 1414 IX	gister mappir	ig illioilliatio	· •	
_ ·	General Device S	<u> </u>					1
bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0
SW_GPIO	PWRDOWN	SYNC_01	SYNC_ 23	SYNC_ALL	EQ_MODE		RSVD
Register 0x01 (	Channel Enable)	R/W					
bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0
				LN_EN_CH3	LN_EN_CH2	LN_EN_CH1	LN_EN_CH0
Register 0x02 (	Channel 0 Contro	ol Settings) R/W					
bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0
RSVD	EQ2	EQ1	EQ0	VOD_CTRL	DC_GAIN	AC_GAIN1	AC_GAIN0
Register 0x03 (	Channel 0 Enable	Settings) R/W					
bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0
					DRV_PEAK	EQ_EN	DRV_EN
Register 0x05 (	Channel 1 Contro	ol Settings) R/W					
bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0
RSVD	EQ2	EQ1	EQ0	VOD_CTRL	DC_GAIN	AC_GAIN1	AC_GAIN0
Register 0x06 (	Channel 1 Enable	Settings) R/W				<u> </u>	
bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0
					DRV_PEAK	EQ_EN	DRV_EN
Register 0x08 (	Channel 2 Contro	ol Settings) R/W					
bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0
RSVD	EQ2	EQ1	EQ0	VOD_CTRL	DC_GAIN	AC_GAIN1	AC_GAIN0
Register 0x09 (	Channel 2 Enable	Settings) R/W					
bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0
					DRV_PEAK	EQ_EN	DRV_EN
Register 0x0B	Channel 3 Contro	ol Settings) R/W				<u> </u>	
bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0
RSVD	EQ2	EQ1	EQ0	VOD_CTRL	DC_GAIN	AC_GAIN1	AC_GAIN0
Register 0x0C	Channel 3 Enable	e Settings) R/W					
bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0
					DRV_PEAK	EQ_EN	DRV_EN
Register 0x0F F	Read Only	•					
bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0
RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD
Register 0x11 F	R/W						
bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0
	RSVD						
Register 0x12 F		ı		<u> </u>	l .	l .	1
bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0
RSVD							20



# Table 5. SN65LVCP1414 Register Description

REGISTER	BIT	SYMBOL	FUNCTION	DEFAULT
	7	SW_GPIO	Switching logic is controlled by GPIO or I <sup>2</sup> C: 0 = I <sup>2</sup> C control 1 = GPIO control	
	6	PWRDOWN	Power down the device: 0 = Normal operation 1 = Powerdown	
	5	SYNC_01	All settings from channel 1 will be used for channel 0 and 1:  0 = Channel 0 tracking channel 1 settings  1 = No tracking tracking	
0x00	4	SYNC_23	All settings from channel 2 will be used for channel 2 and 3:  0 = Channel 3 tracking channel 2 settings  1 = No channel tracking	00000000
	3	SYNC_ALL	All settings from channel 1 will be used on all channels:  0 = All channels tracking channel 1  1 = No channel tracking  Overwrites SYNC_01 and SYNC_23	
	2	EQ_MD	Set EQ mode: 0 = Cable mode 1 = Trace mode	
	1			
	0	RSVD	For TI use only	
	7			
	6			
	5			
	4			
	3	LN_EN_CH3	Channel 3 enable: 0 = Enable 1 = Disable	
0x01	2	LN_EN_CH2	Channel 2 enable: 0 = Enable 1 = Disable	00000000
	1	LN_EN_CH1	Channel 1 enable: 0 = Enable 1 = Disable	
	0	LN_EN_CH0	Channel 0 enable: 0 = Enable 1 = Disable	
	7	RSVD		
	6	EQ2	Equalizer adjustment setting:	
	5 EQ1	EQ1	000 = Minimum equalization setting	
0x02 0x05 0x08 0x0B	4	EQ0 111 = Maximum equaliza	111 = Maximum equalization setting	
	3	VOD_CTRL	Channel [x] VOD control: 0 = Low VOD range 1 = High VOD range	00000000
	2	Channel [x] EQ DC gain:  DC_GAIN_CTRL  0 = Set EQ DC gain to 0.5x  1 = Set EQ DC gain to 1x		
	1	AC_GAIN_CTRL1	AC Gain Control:	
	0	AC_GAIN_CTRL0	00 = Low 01 = HiZ 11 = High	



# Table 5. SN65LVCP1414 Register Description (continued)

REGISTER	BIT	SYMBOL	FUNCTION	DEFAULT
	7			
	6			
	5			
	4			
	3			
0x03 0x06 0x09 0x0C	2	DRV_PEAK	Channel [x] driver peaking: 0 = Disables driver Peaking 1 = Enables driver 6db AC Peaking	00000000
0.00	1	EQ_EN	Channel [x] EQ stage enable: 0 = Enable 1 = Disable	
	0	DRV_EN	Channel [x] driver stage enable: 0 = Enable 1 = Disable	
	7	RSVD	For TI use only	
	6	RSVD	For TI use only	
	5	RSVD	For TI use only	
0x0F	4	RSVD	For TI use only	00110000
UXUF	3	RSVD	For TI use only	00110000
	2	RSVD	For TI use only	
	1	RSVD	For TI use only	
	0	RSVD	For TI use only	
	7			
	6	RSVD	For TI use only	
	5			
0x11	4			00000000
UXII	3			0000000
	2			
	1			
	0			
	7	RSVD	For TI use only	
	6			
	5			
0x12	4			00000000
OA12	3			30000000
	2			
	1			
	0			



### **REVISION HISTORY**

CI	hanges from Original (August 2012) to Revision A	Page
•	Changed OUT2_P pin number from 23 to 24	5
•	Changed OUT2_N pin number from 24 to 23	5
•	Changed OUT3_P pin number from 20 to 21	5
•	Changed OUT3_N pin number from 21 to 20	5



### PACKAGE OPTION ADDENDUM

11-Apr-2013

#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	_	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
SN65LVCP1414RLJR	ACTIVE	WQFN	RLJ	38	3000	Green (RoHS	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	LVCP	Samples
						& no Sb/Br)				1414	bampies
SN65LVCP1414RLJT	ACTIVE	WQFN	RLJ	38	250	Green (RoHS	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	LVCP	Samular.
						& no Sb/Br)				1414	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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# PACKAGE MATERIALS INFORMATION

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### TAPE AND REEL INFORMATION





		Dimension designed to accommodate the component width
E	30	Dimension designed to accommodate the component length
K	(0	Dimension designed to accommodate the component thickness
	N	Overall width of the carrier tape
F	21	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

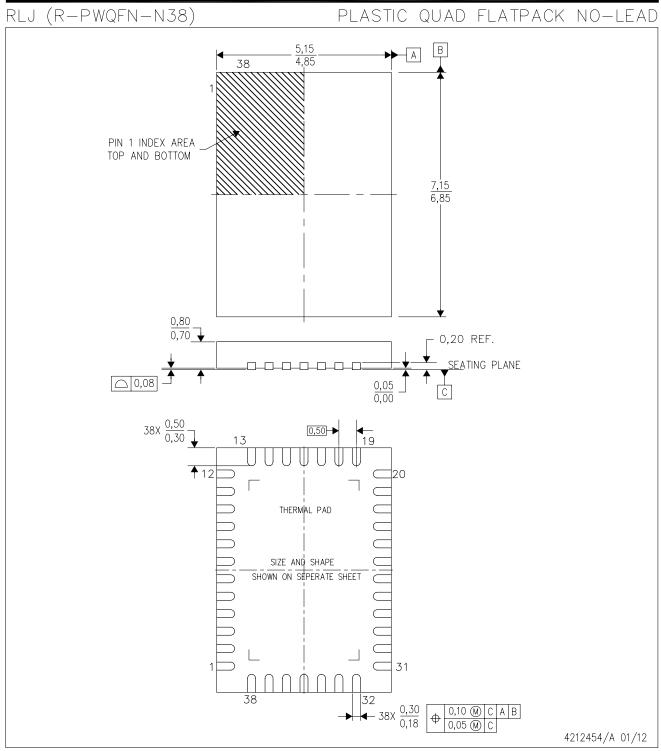
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65LVCP1414RLJR	WQFN	RLJ	38	3000	330.0	16.4	5.25	7.25	1.45	8.0	16.0	Q1
SN65LVCP1414RLJT	WQFN	RLJ	38	250	330.0	16.4	5.25	7.25	1.45	8.0	16.0	Q1

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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65LVCP1414RLJR	WQFN	RLJ	38	3000	367.0	367.0	38.0
SN65LVCP1414RLJT	WQFN	RLJ	38	250	367.0	367.0	38.0



- NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5-1994.
  - B. This drawing is subject to change without notice.
  - C. Quad Flatpack, No-leads (QFN) package configuration.
  - D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
  - E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
  - F. Falls within JEDEC MO-220.



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